

Turbo 2 ultrafast - high voltage rectifier

Main product characteristics

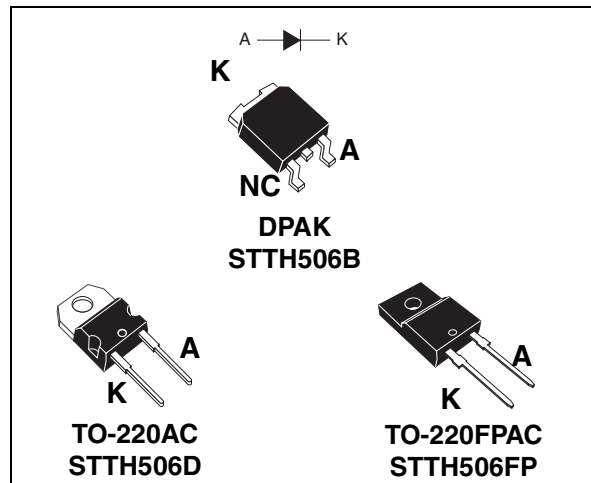
$I_{F(AV)}$	5 A
V_{RRM}	600 V
T_j	175° C
V_F (typ)	1.1 V
t_{rr} (max)	30 ns

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces conduction and switching losses
- Insulated package TO-220FPAC
 - Insulated voltage: 2500 V_{RMS}
 - Typical package capacitance: 12 pF

Description

The STTH506 uses ST Turbo2 600V technology. This device is specially suited for use in switching power supplies, and industrial applications.



Order codes

Part Number	Marking
STTH506B	STTH506B
STTH506B-TR	STTH506B
STTH506D	STTH506D
STTH506FP	STTH506FP

Table 1. Absolute ratings (limiting values per diode at 25° C, unless otherwise specified)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current	TO-220AC, TO220FPAC	20	A
		DPAK	10	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$	$T_c = 145^\circ\text{C}$ TO-220AC, DPAK	5	A
		$T_c = 120^\circ\text{C}$ TO-220FPAC	5	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ ms}$ Sinusoidal TO-220AC, TO220FPAC	70	A
		DPAK	55	A
T_{stg}	Storage temperature range		-65 to + 175	°C
T_j	Maximum operating junction temperature ⁽¹⁾		175	°C

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

1 Characteristics

Table 2. Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AC, DPAK	3.5	°C/W
		TO-220FPAC	6	

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			5	μA
		$T_j = 150^\circ\text{C}$			13	130	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 5\text{ A}$			1.85	V
		$T_j = 150^\circ\text{C}$			1.10	1.40	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$
2. Pulse test: $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 1.07 \times I_{F(AV)} + 0.066 I_F^2(RMS)$$

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 0.5\text{ A}$, $I_{rr} = 0.25\text{ A}$, $I_R = 1\text{ A}$, $T_j = 25^\circ\text{C}$			30	ns
		$I_F = 1\text{ A}$, $di_F/dt = -50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25^\circ\text{C}$		35	50	
I_{RM}	Reverse recovery current	$I_F = 5\text{ A}$, $di_F/dt = -100\text{ A}/\mu\text{s}$, $V_R = 400\text{ V}$, $T_j = 25^\circ\text{C}$		3.5	5	
t_{fr}	Forward recovery time	$I_F = 5\text{ A}$ $di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$, $T_j = 25^\circ\text{C}$			180	ns
V_{FP}	Forward recovery voltage	$I_F = 5\text{ A}$ $di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$, $T_j = 25^\circ\text{C}$		4		V

Figure 1. Conduction losses versus average current

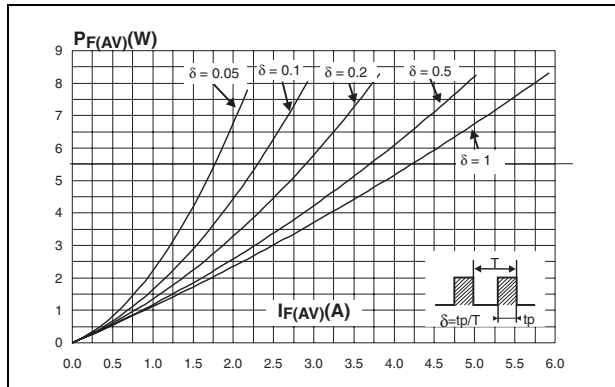


Figure 2. Forward voltage drop versus forward current

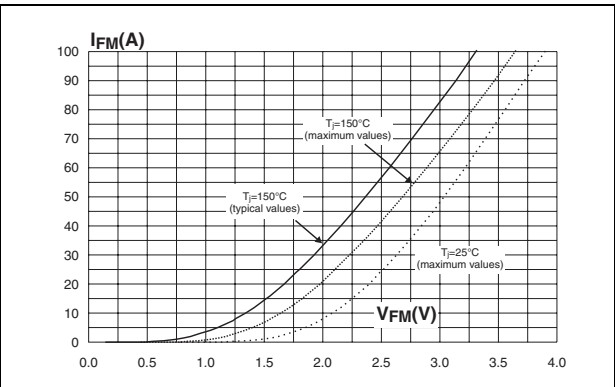


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration (TO-220AC, DPAK)

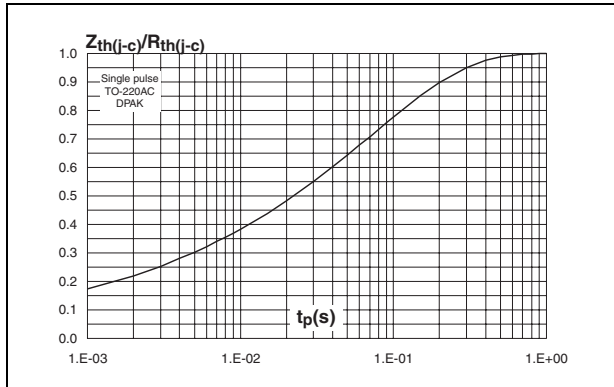


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAC)

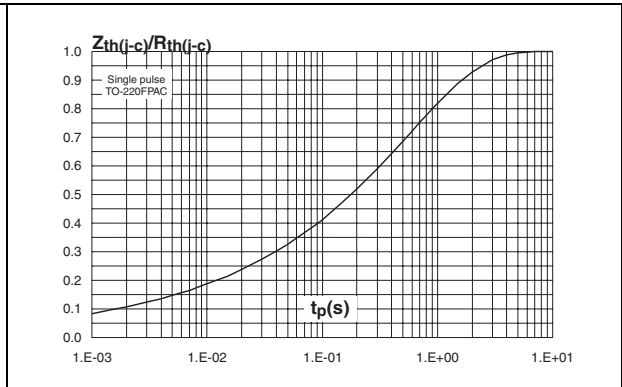


Figure 5. Peak reverse recovery current versus di_F/dt (typical values)

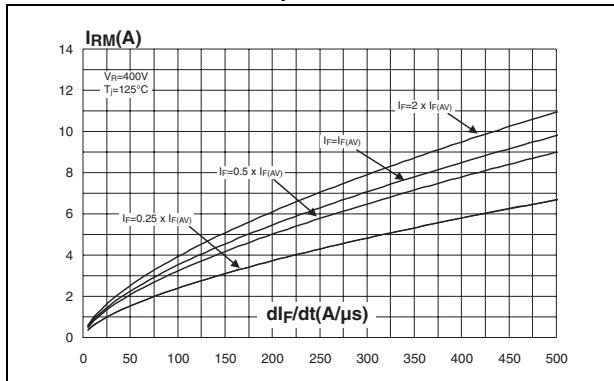


Figure 6. Reverse recovery time versus di_F/dt (typical values)

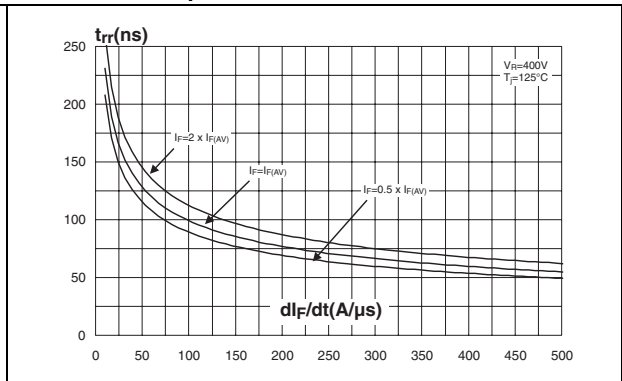


Figure 7. Reverse recovery charges versus di_F/dt (typical values)

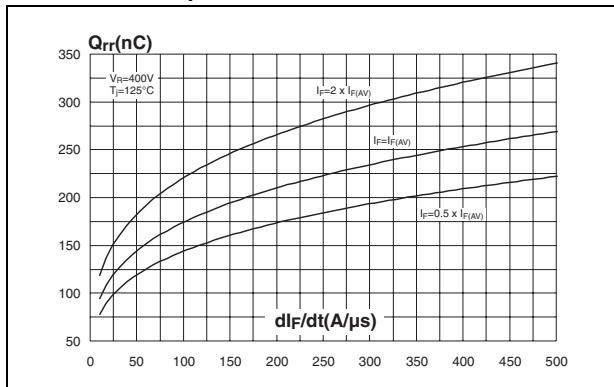


Figure 8. Softness factor versus di_F/dt (typical values)

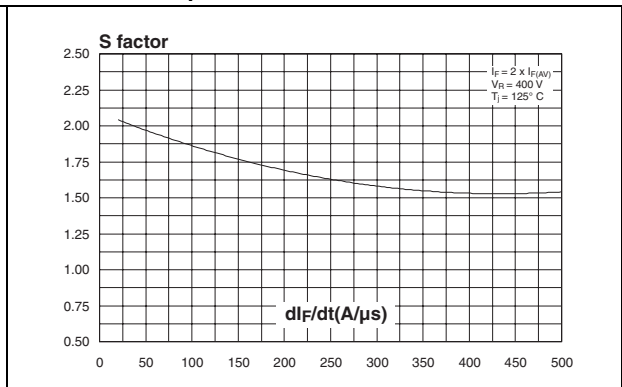


Figure 9. Relative variations of dynamic parameters versus junction temperature

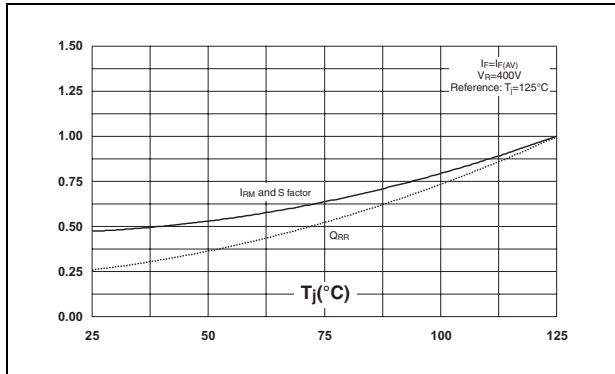


Figure 10. Transient peak forward voltage versus di_F/dt (typical values)

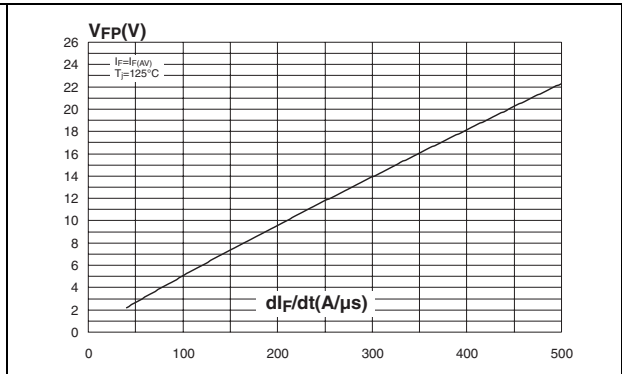


Figure 11. Forward recovery time versus di_F/dt (typical values)

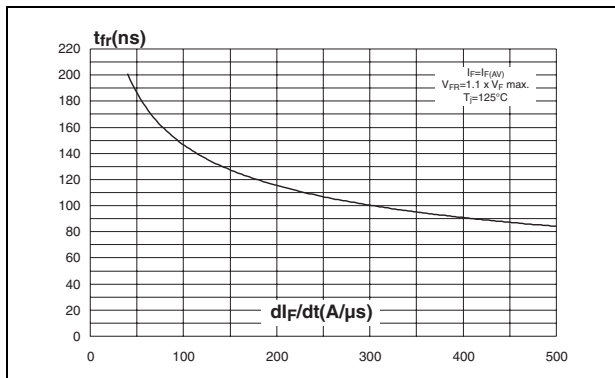


Figure 12. Junction capacitance versus reverse voltage applied (typical values)

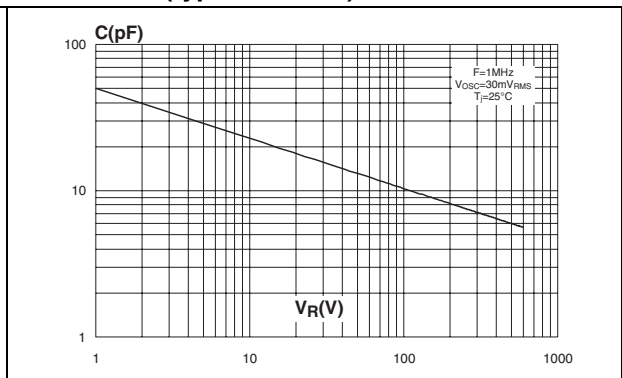
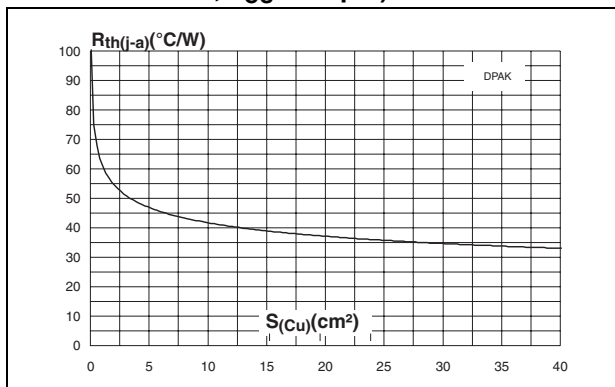


Figure 13. Thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, $e_{Cu} = 35 \mu m$)



2 Package mechanical data

Epoxy meets UL94, V0

Cooling method: by conduction (C)

Recommended torque value: 0.80 Nm

Maximum torque value: 1.0 Nm

Table 5. DPAK Dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max	Min.	Max.
A	2.20	2.40	0.086	0.094
A1	0.90	1.10	0.035	0.043
A2	0.03	0.23	0.001	0.009
B	0.64	0.90	0.025	0.035
B2	5.20	5.40	0.204	0.212
C	0.45	0.60	0.017	0.023
C2	0.48	0.60	0.018	0.023
D	6.00	6.20	0.236	0.244
E	6.40	6.60	0.251	0.259
G	4.40	4.60	0.173	0.181
H	9.35	10.10	0.368	0.397
L2	0.80 typ.		0.031 typ.	
L4	0.60	1.00	0.023	0.039
V2	0°	8°	0°	8°

Figure 14. DPAK Footprint dimensions (in mm)

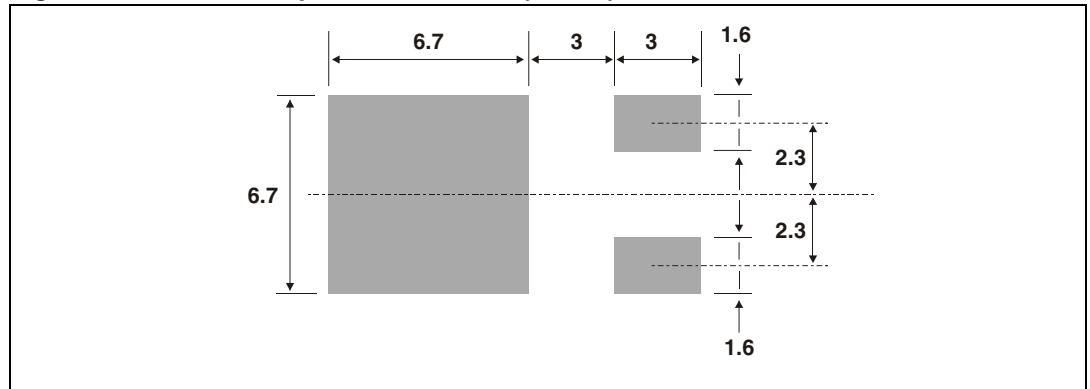


Table 6. TO-220AC Dimensions

The technical drawing shows a TO-220AC package with two views: a front view on the left and a side view on the right. The front view labels dimensions H2 (width), Ø I (lead diameter), L5 (lead length), L6 (body height), L2 (total height), F1 (lead thickness), L9 (lead length from body), L4 (lead length from base), F (lead thickness), and G (lead length from base). The side view labels dimensions A (lead length), C (lead thickness), L7 (lead length), D (lead thickness), M (lead thickness), and E (lead length).

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam. I	3.75	3.85	0.147	0.151

Table 7. TO-220FPAC Dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

3 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH506B	STTH506B	DPAK	0.3 g	75	Tube
STTH506B-TR	STTH506B	DPAK	0.3 g	2500	Tape and reel
STTH506D	STTH506D	TO-220AC	1.86	50	Tube
STTH506FP	STTH506FP	TO-220FPAC	1.8 g	50	Tube

4 Revision history

Date	Revision	Description of Changes
18-May-2006	1	First issue.

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